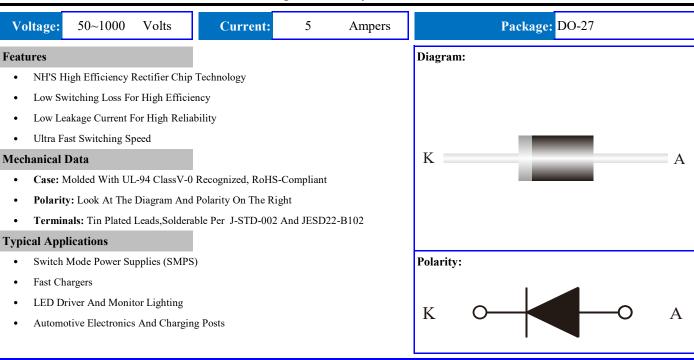




High Efficiency Rectifier



Single Phase, Half Wave, 60Hz, Resistive Or Inductive Load. For Capacitive Load, Derate Current By 20%

Maximum Ratings (Ta=25℃ Unless Otherwise Specified)										
Parameter	<b>Test Conditions</b>	Symbol	HER 501	HER 502	HER 503	HER 505	HER 506	HER 507	HER 508	Unit
Maximum Repetitive Peak Reverse Voltage		$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltag		$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage		$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current		$I_{F(AV)}$				5				A
Peak Forward Surge Current	8.3ms Single Half Sine-wave Superimposed On Rate Load	I <sub>FSM</sub>				125				A
Current Squared Time	t< 8.3ms	I <sup>2</sup> t				64.8				A <sup>2</sup> sec

Electrical Characteristcs (Ta=25°C Unless Otherwise Specified )										
Parameter	Test Conditions	Symbol	HER 501	HER 502	HER 503	HER 505	HER 506	HER 507	HER 508	Unit
Maximum Instaneous Forward Voltage	I <sub>F</sub> = 5.0 A	$V_{\rm F}$	1.00		1.00 1.30 1.70		70	V		
Maximum DC Reverse Current at Rated DC Blocking Voltage	$Ta=25$ °C , $V_R=VRRM$ $Ta=125$ °C , $V_R=VRRM*80$ %	$I_{RRM}$	I <sub>RRM</sub> 5 200			uA uA				
Typical Junction Capacitance	4 V,1MHz	$C_{J}$	60 25		5 20			pF		
Maximum Reverse Recovery Time	IF=0.5A, IR=1.0A, IRR=0.25A	Trr	50 75		75		nS			

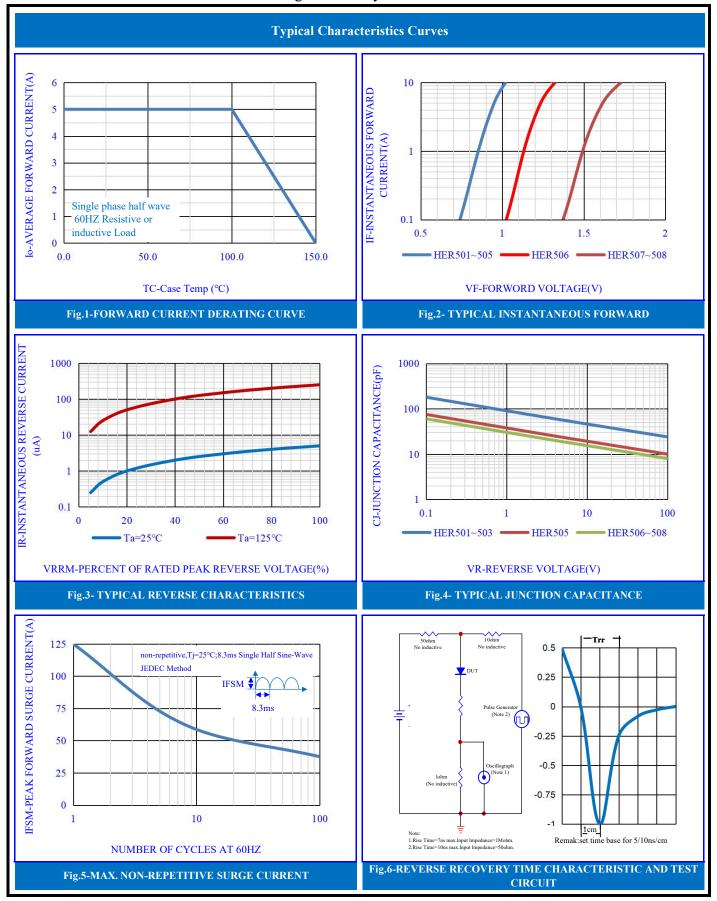
Thermal Characteristcs (Ta=25°C Unless Otherwise Specified )										
Parameter	Test Conditions	Symbol	HER 501	HER 502	HER 503	HER 505	HER 506	HER 507	HER 508	Unit
Operating Junction Temperature Range	T <sub>J</sub> -55~150			က						
Storage Temperature Range		T <sub>STD</sub>	-55~150							
Thermal Resistance Junction To Ambient	Still Air Environment	D	52.0							
With Steady-State	With Steady-State With Ta= $25^{\circ}$ C $R_{0JA}$ 53.0			°C/W						
Thermal Resistance Junction-Case	At 0.375"(9.5mm) lead length	D	<b>P</b> 16.0			C/W				
With Steady-State	Mounted On vertical P.C. Board	$R_{\theta JC}$	16.0							
Notes, 1 Pulse Test, 200 He Pulse Width 10/	Duty Cyala									

Notes: 1.Pulse Test: 300 Us Pulse Width,1% Duty Cycle

# Pb RoHS Pb-Free COMPLIANT

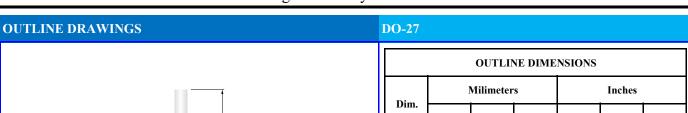
#### HER501 THRU HER508

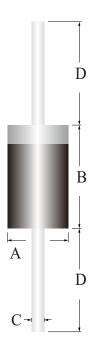
High Efficiency Rectifier





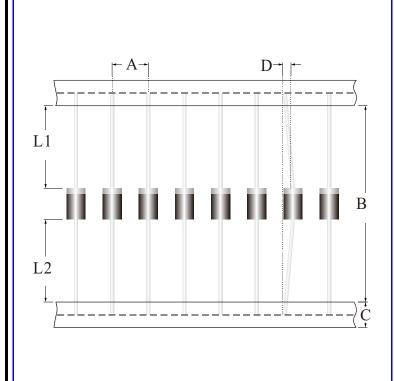






OUTLINE DIMENSIONS								
ъ.	Milimeters Inches							
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.		
A	4.90	-	5.60	0.1929	-	0.2205		
В	8.00	-	10.00	0.3150	ı	0.3937		
С	1.00	-	1.40	0.0394	-	0.0551		
D	24.50	-	26.50	0.9646	-	1.0433		

# COMPONENT PITCH DIMENSION DIAGRAM



#### **DO-27**

OUTLINE DIMENSIONS								
n:	Milimeters			Inches				
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.		
A	9.50	-	10.50	0.3740	ı	0.4134		
В	51.00	-	53.00	2.0079	1	2.0866		
С	5.50	-	6.50	0.2165	1	0.2559		
D	-	-	1.20	-	1	0.0472		
L2-L1	-	-	1.00	-	1	0.0394		





High Efficiency Rectifier

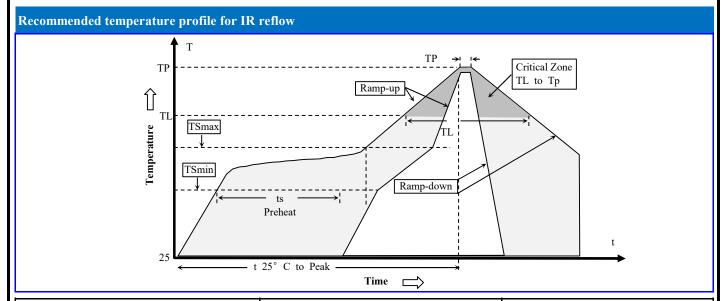
MARKING	MARKING INSTRUCTION
HER5xx	NH=Niuhang Trademark FF=Product Line Code,According To Actual Changes DDK=Inernal Code,According To Actual Changes HER5xx=Modelx=01,02,03,05,06,07,08 White band denotes cathode

PACKING INFORMATION								
Package Type	Package Code	Productor Weight Approx(g/Pcs)	Package Method	Quantity (Pcs/Min. Pack.)	Quantity (Pcs/Inner Box)	Quantity (Pcs/Carton)		
DO-27	P1	1	Tube	1000	1000	20000		
DO-27	P2	1	Tape	1250	1250	12500		



## High Efficiency Rectifier

Recommended wave soldering condition							
Product	Peak Temperature	Soldering Time					
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds					



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.
Preheat  -Temperature Min(TS min)  -Temperature Max(TS max)  -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above:  -Temperature (TL)  - Time (tL)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note: All temperatures refer to topside of the package, measured on the package body surface.



## High Efficiency Rectifier

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